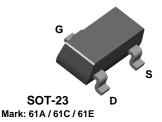


PN4117 **PN4118 PN4119** 

## **MMBF4117 MMBF4118 MMBF4119**





NOTE: Source & Drain are interchangeable

## **N-Channel Switch**

This device is designed for low current DC and audio applications. These devices provide excellent performance as input stages for sub-picoamp instrumentation or any high impedance signal sources. Sourced from Process 53.

### **Absolute Maximum Ratings\*** TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{DG}$	Drain-Gate Voltage	40	V
V <sub>GS</sub>	Gate-Source Voltage	- 40	V
I <sub>GF</sub>	Forward Gate Current	50	mA
T <sub>J</sub> ,T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### **Thermal Characteristics** TA = 25°C unless otherwise noted

Symbol	Characteristic	N	Units	
		PN4117-4119	*MMBF4117-4119	
$P_D$	Total Device Dissipation Derate above 25°C	350 2.8	225 1.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	357	556	°C/W

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

### **N-Channel Switch**

10

3.0

1.5

μmhos

μmhos

μmhos

μmhos pF

рF

(continued)

Symbol	Parameter	Test Conditions	Min	Max	Units
OFF CHAI	RACTERISTICS				
V <sub>(BR)GSS</sub>	Gate-Source Breakdown Voltage	$I_G = -1.0  \mu A,  V_{DS} = 0$	- 40		V
I <sub>GSS</sub>	Gate Reverse Current	V <sub>GS</sub> = - 20 V, V <sub>DS</sub> = 0		- 10	pА
		$V_{GS} = -20 \text{ V}, V_{DS} = 0, T_A = 150^{\circ}\text{C}$		- 25	nA
$V_{GS(off)}$	Gate-Source Cutoff Voltage	$V_{DS} = -10 \text{ V}, I_D = 1.0 \text{ nA}$ 4117	- 0.6	- 1.8	V
		4118	- 1.0	- 3.0	V
		4119	- 2.0	- 6.0	V
	ACTEDICTION				
ON CHAR I <sub>DSS</sub>	ACTERISTICS  Zero-Gate Voltage Drain Current*	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0 4117 4118	30 80 300	90 240 600	μΑ μΑ
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current*	,			
loss	Zero-Gate Voltage Drain Current*  IGNAL CHARACTERISTICS	4118 4119	80	240	μA
I <sub>DSS</sub> SMALL-S	Zero-Gate Voltage Drain Current*  IGNAL CHARACTERISTICS  Common-Source Forward	4118 4119 V <sub>DS</sub> = 10 V V <sub>GS</sub> = 0, f= 1.0 kHz	80 200	240 600	μΑ μΑ
I <sub>DSS</sub> SMALL-S	Zero-Gate Voltage Drain Current*  IGNAL CHARACTERISTICS	V <sub>DS</sub> = 10 V V <sub>GS</sub> = 0, f= 1.0 kHz 4117	80 200 70	240 600	μΑ μΑ μmhos
SMALL-S	Zero-Gate Voltage Drain Current*  IGNAL CHARACTERISTICS  Common-Source Forward	V <sub>DS</sub> = 10 V V <sub>GS</sub> = 0, f= 1.0 kHz 4117 4118	80 200 70 80	240 600 210 250	μΑ μΑ μmhos μmhos
SMALL-S	Zero-Gate Voltage Drain Current*  IGNAL CHARACTERISTICS  Common-Source Forward Transconductance	V <sub>DS</sub> = 10 V V <sub>GS</sub> = 0, f= 1.0 kHz 4117 4118 4119	80 200 70	240 600	μΑ μΑ μmhos
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current*  IGNAL CHARACTERISTICS  Common-Source Forward	V <sub>DS</sub> = 10 V V <sub>GS</sub> = 0, f= 1.0 kHz 4117 4118	80 200 70 80	240 600 210 250	μΑ μΑ μmhos μmhos

4119

4117

4118

4119

60

70

90

 $V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 30 \text{ MHz}$ 

 $V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1.0 \text{ kHz}$ 

 $V_{DS} = 10 \text{ V}, V_{GS} = 0, f = 1.0 \text{ MHz},$ 

R<sub>e(yfs)</sub>

 $C_{\text{iss}}$ 

 $C_{\text{rss}}$ 

Common-Source Forwad

Reverse Transfer Capacitance

Transconductance

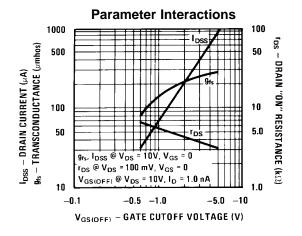
Input Capacitance

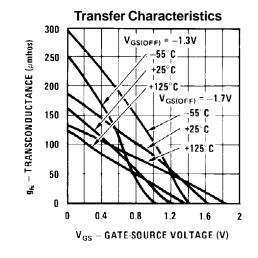
<sup>\*</sup>Pulse Test: Pulse Width  $\leq\!300\,\mu\text{s},\,\text{Duty Cycle}\,\!\leq\!1.0\%$ 

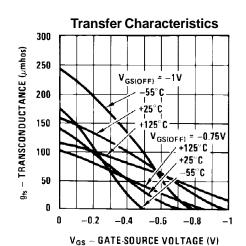
### **N-Channel Switch**

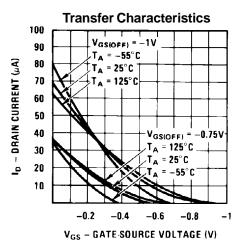
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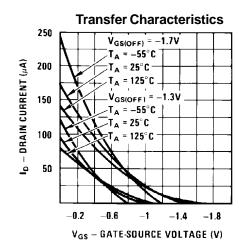
### **Typical Characteristics**

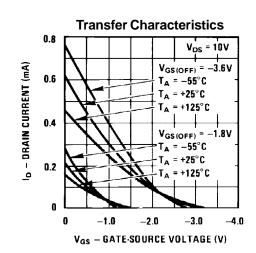








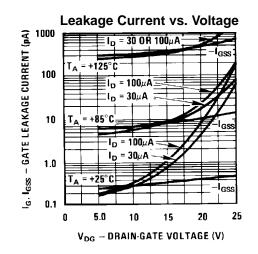


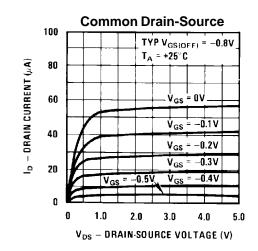


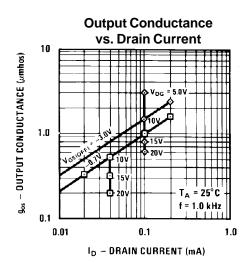
### **N-Channel Switch**

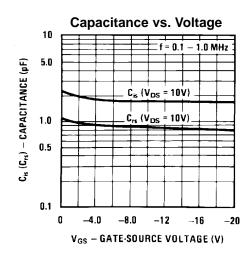
(continued)

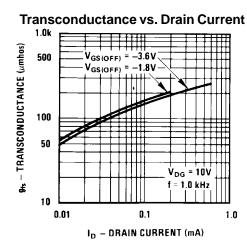
### Typical Characteristics (continued)

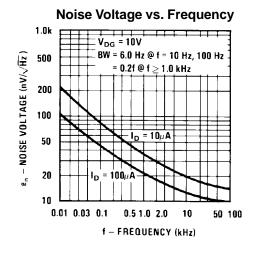










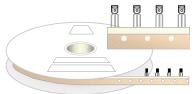


### **TO-92 Tape and Reel Data** FAIRCHILD SEMICONDUCTOR TM **TO-92 Packaging** Configuration: Figure 1.0 **TAPE and REEL OPTION** FSCINT Label sample See Fig 2.0 for various Reeling Styles CBVK//418019 **FSCINT** Label 5 Reels per Intermediate Box Customized F63TNR Label sample Label F63TNR LOT: CBVK741B019 QTY: 2000 FSID: PN222N Customized QTY1: QTY2: Label 375mm x 267mm x 375mm Intermediate Box TO-92 TNR/AMMO PACKING INFROMATION **AMMO PACK OPTION** See Fig 3.0 for 2 Ammo Packing Style Quantity EOL code **Pack Options** 2,000 D26Z Е 2,000 D27Z Ammo М 2,000 D74Z D75Z 2,000 **FSCINT** Unit weight = 0.22 gm Reel weight with components = 1.04 kg Ammo weight with components = 1.02 kg Max quantity per intermediate box = 10,000 units Label 5 Ammo boxes per Intermediate Box 327mm x 158mm x 135mm Immediate Box Customized F63TNR Customized Label Label 333mm x 231mm x 183mm Intermediate Box (TO-92) BULK PACKING INFORMATION **BULK OPTION** See Bulk Packing DESCRIPTION QUANTITY Information table J18Z TO-18 OPTION STD 2.0 K / BOX Anti-static Bubble Sheets TO-5 OPTION STD NO LEAD CLIP 1.5 K / BOX J05Z **FSCINT Label** NO EOL TO-92 STANDARD STRAIGHT FOR: PKG 92, NO LEADCLIP 2.0 K / BOX 94 (NON PROELECTRON SERIES), 96 TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98 L34Z NO LEADCLIP 2.0 K / BOX 2000 units per 114mm x 102mm x 51mm EO70 box for std option Immediate Box 5 EO70 boxes per intermediate Box 530mm x 130mm x 83mm Customized Intermediate box Label FSCINT Label 10,000 units maximum per intermediate box for std option

### TO-92 Tape and Reel Data, continued

# **TO-92 Reeling Style Configuration:** Figure 2.0

### Machine Option "A" (H)

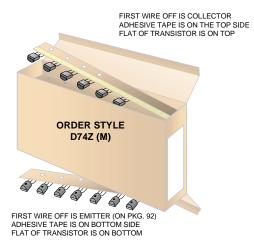


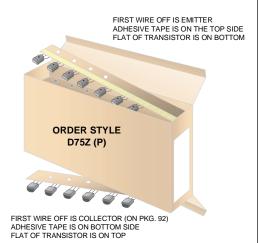
Style "A", D26Z, D70Z (s/h)

# Machine Option "E" (J)

Style "E", D27Z, D71Z (s/h)

# **TO-92 Radial Ammo Packaging Configuration:** Figure 3.0





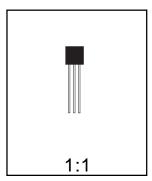


## **TO-92 Package Dimensions**



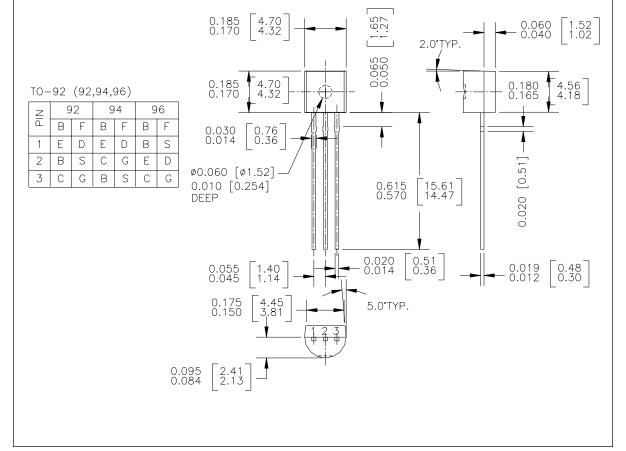
# TO-92 (FS PKG Code 92, 94, 96)

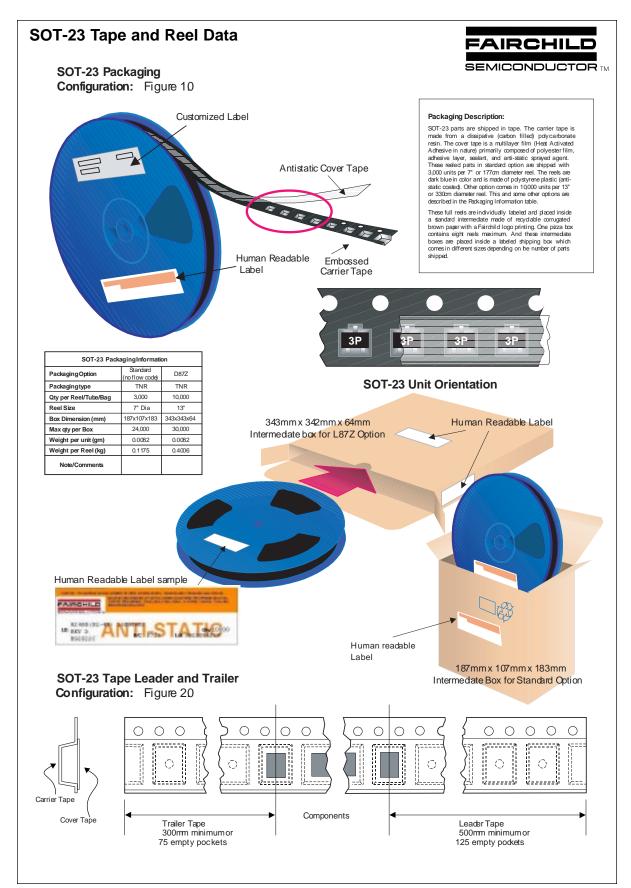




Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977

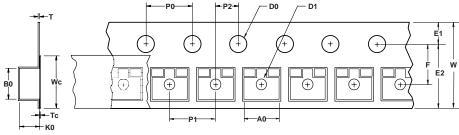




## SOT-23 Tape and Reel Data, continued

### **SOT-23 Embossed Carrier Tape**

Configuration: Figure 3.0



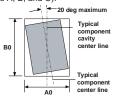
User Direction of Feed

	Dimensions are in millimeter													
Pkg type	Α0	В0	w	D0	D1	E1	E2	F	P1	P0	K0	Т	Wc	Тс
<b>SOT-23</b> (8mm)	3.15 +/-0.10	2.77 +/-0.10	8.0 +/-0.3	1.55 +/-0.05	1.125 +/-0.125	1.75 +/-0.10	6.25 min	3.50 +/-0.05	4.0 +/-0.1	4.0 +/-0.1	1.30 +/-0.10	0.228 +/-0.013	5.2 +/-0.3	0.06 +/-0.02

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation

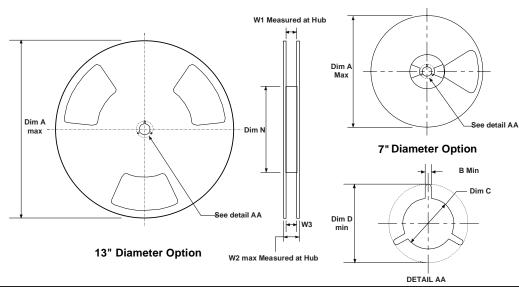


Sketch B (Top View)
Component Rotation



Sketch C (Top View)
Component lateral movement

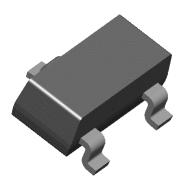
### SOT-23 Reel Configuration: Figure 4.0

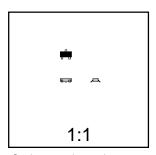


Dimensions are in inches and millimeters									
Tape Size	Reel Option	Dim A	Dim B	Dim C	Dim D	Dim N	Dim W1	Dim W2	Dim W3 (LSL-USL)
8mm	7" Dia	7.00 177.8	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	2.165 55	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9
8mm	13" Dia	13.00 330	0.059 1.5	512 +0.020/-0.008 13 +0.5/-0.2	0.795 20.2	4.00 100	0.331 +0.059/-0.000 8.4 +1.5/0	0.567 14.4	0.311 - 0.429 7.9 - 10.9



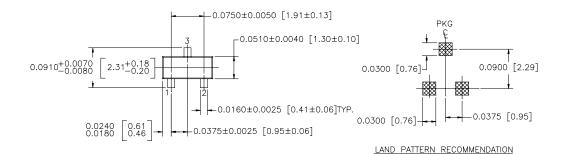
# SOT-23 (FS PKG Code 49)

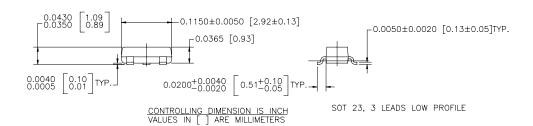




Scale 1:1 on letter size paper Dimensions shown below are in:

inches [millimeters]
Part Weight per unit (gram): 0.0082





NOTE: UNLESS OTHERWISE SPECIFIED

- 1. STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.				
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.				